

# AC Input, Half Pitch Mini-Flat Package 4-Pin Optocoupler

# **HMHAA280**

#### **Description**

The HMHAA280 series consists of two gallium arsenide infrared emitting diodes, connected in inverse parallel, driving a single silicon phototransistor in a compact 4-pin mini-flat package. The lead pitch is 1.27 mm.

#### **Features**

- Compact 4-pin Package (2.4 mm Maximum Standoff Height)
- Half Pitch Leads for Optimum Board Space Savings
- Current Transfer Ratio: 50–600%
- Available in Tape and Reel Quantities of 2500
- CSA (File #1201524), UL (File #E90700) and VDE (File #136480)
   Certified
- This is a Pb-Free Device

#### **Applications**

- AC Line Monitor
- Unknown Polarity DC Sensor
- Telephone Line Receiver



MPF4 CASE 100AL

#### **MARKING DIAGRAM**



ON = onsemi Logo

280 = Device Number

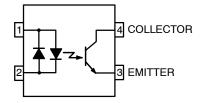
 V = VDE mark (Note: Only appears on parts ordered with VDE option – See order entry table)

X = One-Digit Year Code

YY = Digit Work Week, Ranging from "01" to "53"

M1 = Assembly Package Code

#### PIN CONNECTIONS



#### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 5 of this data sheet.

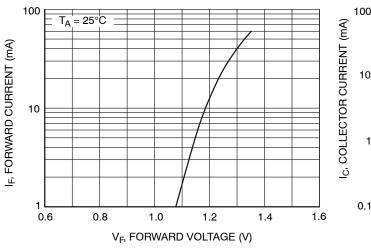
## **ABSOLUTE MAXIMUM RATINGS** ( $T_A = 25$ °C, unless otherwise noted)

Symbol	Parameter	Value	Unit
TOTAL PAG	CKAGE		•
T <sub>STG</sub>	Storage Temperature	-55 to + 125	°C
T <sub>OPR</sub>	Operating Temperature	-55 to + 100	°C
EMITTER			
I <sub>F (avg)</sub>	Continuous Forward Current	50	mA
I <sub>F (pk)</sub>	Peak Forward Current (1µs pulse, 300 pps.)	1	Α
V <sub>R</sub>	Reverse Input Voltage	6	V
P <sub>D</sub>	Power Dissipation Derate Linearly (above 25°C)	60 0.6	mW mW/°0
DETECTOR	R		
	Continuous Collector Current	50	mA
$P_{D}$	Power Dissipation Derate Linearly (above 25°C)	150 1.5	mW mW/°(
$V_{CEO}$	Collector-Emitter Voltage	80	V
V <sub>ECO</sub>	Emitter-Collector Voltage	7	V

Symbol	Parameter	Test Condition	Min	Тур	Max	Unit
INDIVIDUA Emitter	L COMPONENT CHARACTERISTICS			•		•
V <sub>F</sub>	Forward Voltage	I <sub>F</sub> = ±5 mA	-	-	1.4	V
I <sub>R</sub>	Reverse Current	V <sub>R</sub> = 5 V	-	-	5	μΑ
Detector		•				
BV <sub>CEO</sub>	Breakdown Voltage Collector to Emitter	I <sub>C</sub> = 0.5 mA, I <sub>F</sub> = 0	80	-	-	V
BV <sub>ECO</sub>	Emitter to Collector	I <sub>E</sub> = 100 μA, I <sub>F</sub> = 0	7	-	_	
I <sub>CEO</sub>	Collector Dark Current	V <sub>CE</sub> = 80 V, I <sub>F</sub> = 0	-	-	100	nA
C <sub>CE</sub>	Capacitance	V <sub>CE</sub> = 0 V, f = 1 MHz	_	10	_	pF
TRANSFER	CHARACTERISTICS	•			-	
CTR	DC Current Transfer Ratio	$I_F = \pm 5$ mA, $V_{CE} = 5$ V	50	-	600	%
	CTR Symmetry	$I_F = \pm 5$ mA, $V_{CE} = 5$ V	0.33	-	3.0	
V <sub>CE(SAT)</sub>	Saturation Voltage	$I_F = \pm 8 \text{ mA}, I_C = 2.4 \text{ mA}$	-	-	0.4	V
t <sub>r</sub>	Rise Time (Non-Saturated)	$I_C$ = 2 mA, $V_{CE}$ = 5 V, $R_L$ = 100 $\Omega$	-	3	_	μS
t <sub>f</sub>	Fall Time (Non-Saturated)	$I_C$ = 2 mA, $V_{CE}$ = 5 V, $R_L$ = 100 $\Omega$	-	3	-	μs
SOLATION	CHARACTERISTICS	•			•	•
V <sub>ISO</sub>	Steady State Isolation Voltage	1 Minute	3750	-	_	VRMS

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. \*All typicals at  $T_A = 25$ °C.

#### TYPICAL PERFORMANCE CHARACTERISTICS



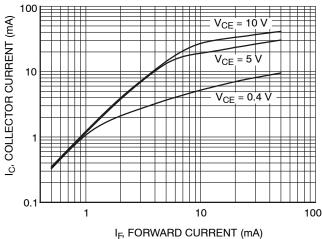
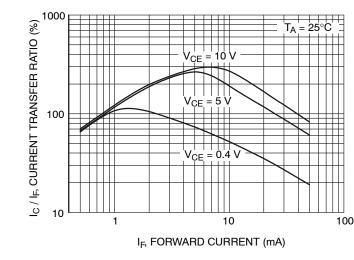


Figure 1. Forward Current vs. Forward Voltage

Figure 2. Collector Current vs. Forward Current



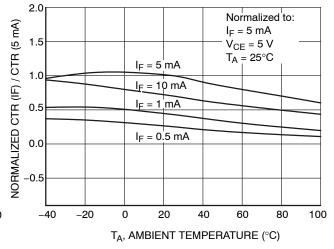


Figure 3. Current Transfer Ratio vs. Forward Current

Figure 4. Normalized CTR vs. Temperature

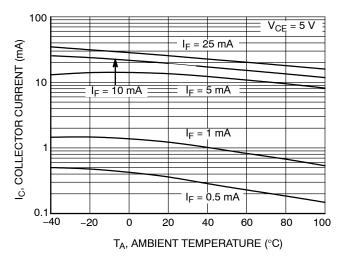


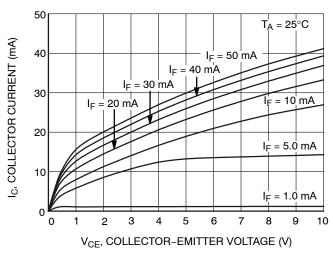
Figure 5. Collector Current vs. Temperature

### TYPICAL PERFORMANCE CHARACTERISTICS (continued)

18

16

14



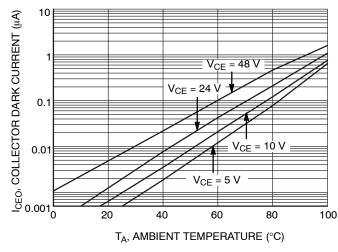
I<sub>C</sub>, COLLECTOR CURRENT (mA)  $I_F = 3'0 \text{ mA}$ 12  $I_F = 20 \text{ mA}$ 10 = 10 m/s8 Î<sub>F</sub> = 5 mA 6  $I_F = 2 \text{ m/A}$  $l_F = 0.5 \text{ m/s}$ 2  $I_{F} = 1.0 \text{ mA}$ 0.0 0.2 1.0 0.4 0.6 8.0  $V_{CE}$ , COLLECTOR-EMITTER VOLTAGE (V)

= 40 <sup>'</sup>mA

I<sub>F</sub> = 50 mA

Figure 6. Collector Current vs. Collector-Emitter Voltage

Figure 7. Collector Current vs. Collector-Emitter Voltage



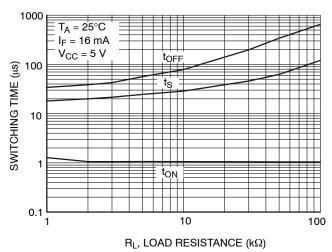


Figure 8. Collector Dark Current vs. Temperature

Figure 9. Switching Time vs. Load Resistance

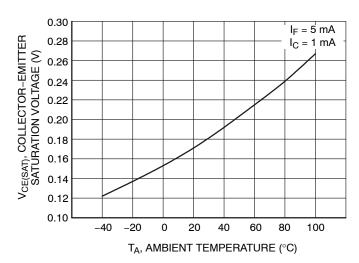
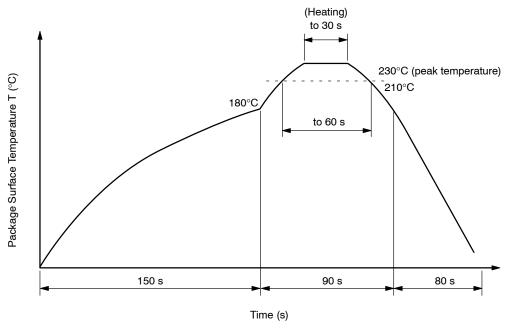


Figure 10. Collector-Emitter Saturation Voltage vs. Temperature

### **REFLOW PROFILE**



- Peak reflow temperature: 230°C (package surface temperature) for 30 seconds
- Time of temperature higher than 210°C: 60 seconds or less
- One time soldering reflow is recommended

### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>	
HMHAA280	MFP-4	150 Units / Tube	
HMHAA280R2	MFP-4	2500 / Tape & Reel	
HMHAA280R2V	MFP-4, VDE Option	2500 / Tape & Reel	
HMHAA280V	MFP-4, VDE Option	150 Units / Tube	

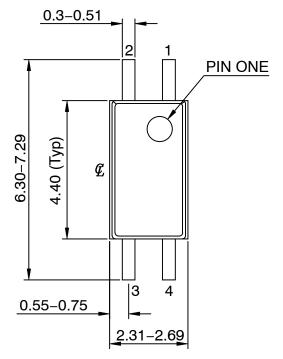
<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, <a href="https://example.com/BRD8011/D">BRD8011/D</a>.

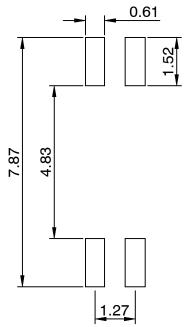
<sup>\*</sup>For applications requiring 260C peak reflow performance, please order FODM214 series.

**DATE 31 AUG 2016** 

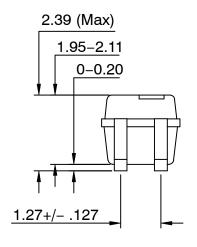


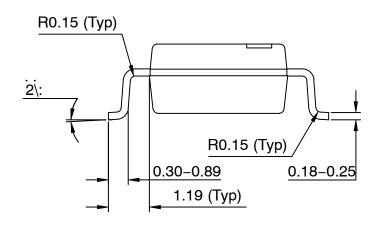
#### MFP4 2.5X4.4, 1.27P CASE 100AL ISSUE O





LAND PATTERN RECOMMENDATION





### NOTES:

- A) NO STANDARD APPLIES TO THIS PACKAGE
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSION

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